



# BFR540

## NPN 9 GHz wideband transistor

Rev. 6 — 13 September 2011

Product data sheet

## 1. Product profile

### 1.1 General description

The BFR540 is an NPN silicon planar epitaxial transistor in a SOT23 plastic package.

### 1.2 Features and benefits

- High power gain
- Low noise figure
- High transition frequency
- Gold metallization ensures excellent reliability.

### 1.3 Applications

- RF front end wideband applications in the GHz range
  - ◆ Analog and digital cellular telephones
  - ◆ Cordless telephones (CT1, CT2, DECT, etc.)
  - ◆ Radar detectors
  - ◆ Satellite TV tuners (SATV)
  - ◆ MATV/CATV amplifiers
  - ◆ Repeater amplifiers in fiber-optic systems.

### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter	-	-	20	V
$V_{CES}$	collector-emitter voltage	$R_{BE} = 0 \Omega$	-	-	15	V
$I_C$	collector current (DC)		-	-	120	mA
$P_{tot}$	total power dissipation	$T_{sp} \leq 70 \text{ }^\circ\text{C}$	[1]	-	500	mW
$h_{FE}$	DC current gain	$I_C = 40 \text{ mA}; V_{CE} = 8 \text{ V}$	100	120	250	
$C_{re}$	feedback capacitance	$I_C = i_c = 0 \text{ A}; V_{CB} = 8 \text{ V}; f = 1 \text{ MHz}$	-	0.6	-	pF
$f_T$	transition frequency	$I_C = 40 \text{ mA}; V_{CE} = 8 \text{ V}; f = 1 \text{ GHz}$	-	9	-	GHz
$G_{UM}$	maximum unilateral power gain	$I_C = 40 \text{ mA}; V_{CE} = 8 \text{ V}; T_{amb} = 25 \text{ }^\circ\text{C}$				
		$f = 900 \text{ MHz}$	-	14	-	dB
		$f = 2 \text{ GHz}$	-	7	-	dB



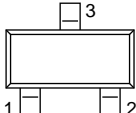
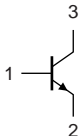
Table 1. Quick reference data ...continued

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$ s_{21} ^2$	insertion power gain	$I_C = 40 \text{ mA}$ ; $V_{CE} = 8 \text{ V}$ ; $T_{amb} = 25 \text{ }^\circ\text{C}$ ; $f = 900 \text{ MHz}$	12	13	-	dB
NF	noise figure	$\Gamma_s = \Gamma_{opt}$ ; $V_{CE} = 8 \text{ V}$ ; $T_{amb} = 25 \text{ }^\circ\text{C}$				
		$I_C = 10 \text{ mA}$ ; $f = 900 \text{ MHz}$	-	1.3	1.8	dB
		$I_C = 40 \text{ mA}$ ; $f = 900 \text{ MHz}$	-	1.9	2.4	dB
		$I_C = 10 \text{ mA}$ ; $f = 2 \text{ GHz}$	-	2.1	-	dB

[1]  $T_{sp}$  is the temperature at the soldering point of the collector tab.

## 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Symbol
1	base		
2	emitter		
3	collector		

*sym021*

## 3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BFR540	-	plastic surface mounted package; 3 leads	SOT23

## 4. Marking

Table 4. Marking

Type number	Marking code <sup>[1]</sup>
BFR540	33*

[1] \* = p: Made in Hong Kong  
 \* = t: Made in Malaysia  
 \* = W: Made in China.

## 5. Limiting values

**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter	-	20	V
$V_{CES}$	collector-emitter voltage	$R_{BE} = 0 \Omega$	-	15	V
$V_{EBO}$	emitter-base voltage	open collector	-	2.5	V
$I_C$	collector current (DC)		-	120	mA
$P_{tot}$	total power dissipation	$T_{sp} \leq 70 \text{ }^\circ\text{C}$	[1]	500	mW
$T_{stg}$	storage temperature		-65	+150	$^\circ\text{C}$
$T_j$	junction temperature		-	175	$^\circ\text{C}$

[1]  $T_{sp}$  is the temperature at the soldering point of the collector tab.

## 6. Thermal characteristics

**Table 6. Thermal characteristics**

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-sp)}$	thermal resistance from junction to soldering point		[1]	260 K/W

[1]  $T_{sp}$  is the temperature at the soldering point of the collector tab.

## 7. Characteristics

**Table 7. Characteristics**

$T_j = 25 \text{ }^\circ\text{C}$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$I_{CBO}$	collector cut-off current	$I_E = 0 \text{ A}; V_{CB} = 8 \text{ V}$	-	-	50	nA
$h_{FE}$	DC current gain	$I_C = 40 \text{ mA}; V_{CE} = 8 \text{ V}$	100	120	250	
$C_e$	emitter capacitance	$I_C = i_c = 0 \text{ A}; V_{EB} = 0.5 \text{ V};$ $f = 1 \text{ MHz}$	-	2	-	pF
$C_c$	collector capacitance	$I_E = i_e = 0 \text{ A}; V_{CB} = 8 \text{ V};$ $f = 1 \text{ MHz}$	-	0.9	-	pF
$C_{re}$	feedback capacitance	$I_C = 0 \text{ A}; V_{CB} = 8 \text{ V};$ $f = 1 \text{ MHz}$	-	0.6	-	pF
$f_T$	transition frequency	$I_C = 40 \text{ mA}; V_{CE} = 8 \text{ V};$ $f = 1 \text{ GHz}$	-	9	-	GHz
$G_{UM}$	maximum unilateral power gain	$I_C = 40 \text{ mA}; V_{CE} = 8 \text{ V};$ $T_{amb} = 25 \text{ }^\circ\text{C}$	[1]			
		$f = 900 \text{ MHz}$	-	14	-	dB
		$f = 2 \text{ GHz}$	-	7	-	dB
$ S_{21} ^2$	insertion power gain	$I_C = 40 \text{ mA}; V_{CE} = 8 \text{ V};$ $T_{amb} = 25 \text{ }^\circ\text{C}; f = 900 \text{ MHz}$	12	13	-	dB

**Table 7. Characteristics ...continued**  
*T<sub>j</sub> = 25 °C unless otherwise specified.*

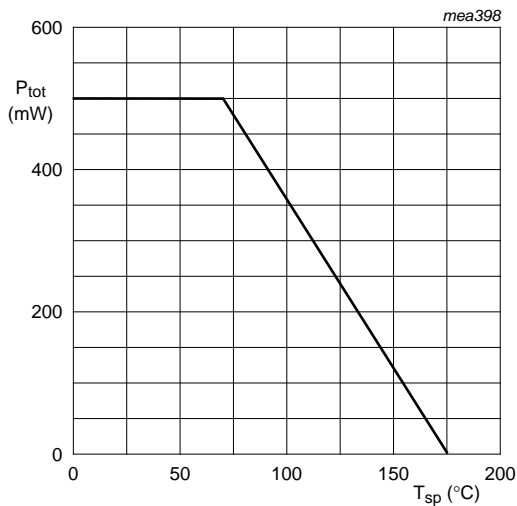
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
NF	noise figure	$\Gamma_s = \Gamma_{opt}$ ; $V_{CE} = 8\text{ V}$ ; $T_{amb} = 25\text{ °C}$				
		$I_C = 10\text{ mA}$ ; $f = 900\text{ MHz}$	-	1.3	1.8	dB
		$I_C = 40\text{ mA}$ ; $f = 900\text{ MHz}$	-	1.9	2.4	dB
		$I_C = 10\text{ mA}$ ; $f = 2\text{ GHz}$	-	2.1	-	dB
$P_{L(1dB)}$	output power at 1 dB gain compression	$I_C = 40\text{ mA}$ ; $V_{CE} = 8\text{ V}$ ; $R_L = 50\ \Omega$ ; $T_{amb} = 25\text{ °C}$ ; $f = 900\text{ MHz}$	-	21	-	dBm
I/O	third order intercept point		[2]	34	-	dBm
$V_O$	output voltage	$I_C = 40\text{ mA}$ ; $V_{CE} = 8\text{ V}$ ; $Z_L = Z_S = 75\ \Omega$ ; $T_{amb} = 25\text{ °C}$	[3]	550	-	mV

[1]  $G_{UM}$  is the maximum unilateral power gain, assuming  $s_{12}$  is zero and

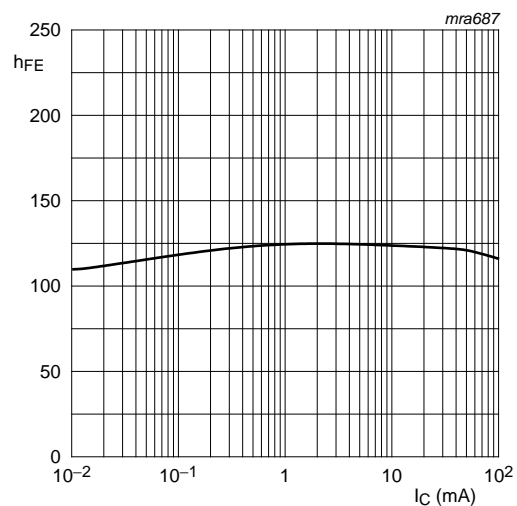
$$G_{UM} = 10 \log \frac{|s_{21}|^2}{(1 - |s_{11}|^2)(1 - |s_{22}|^2)} \text{ dB.}$$

[2]  $I_C = 40\text{ mA}$ ;  $V_{CE} = 8\text{ V}$ ;  $R_L = 50\ \Omega$ ;  $T_{amb} = 25\text{ °C}$ ;  $f = 900\text{ MHz}$ ;  $f_p = 900\text{ MHz}$ ;  $f_q = 902\text{ MHz}$ .  
 Measured at  $f_{(2p-q)} = 898\text{ MHz}$  and  $f_{(2q-p)} = 904\text{ MHz}$ .

[3]  $d_{im} = -60\text{ dB}$  (DIN 45004B);  $V_p = V_O$ ;  $V_q = V_O - 6\text{ dB}$ ;  $f_p = 795.25\text{ MHz}$ ;  $V_R = V_O - 6\text{ dB}$ ;  $f_q = 803.25\text{ MHz}$ ;  
 $f_r = 805.25\text{ MHz}$ .  
 Measured at  $f_{(p+q-r)} = 793.25\text{ MHz}$ .

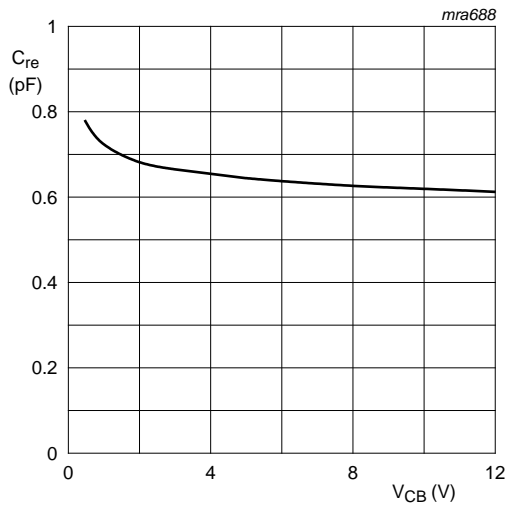


**Fig 1. Power derating curve.**



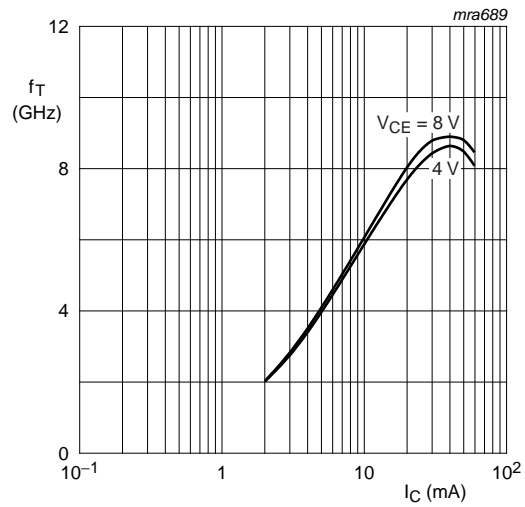
$V_{CE} = 8\text{ V}$ .

**Fig 2. DC current gain as a function of collector current.**



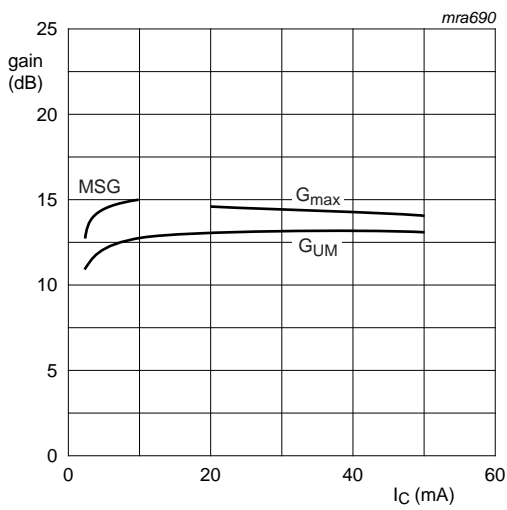
$I_C = 0$  A;  $f = 1$  MHz.

**Fig. 3. Feedback capacitance as a function of collector-base voltage.**



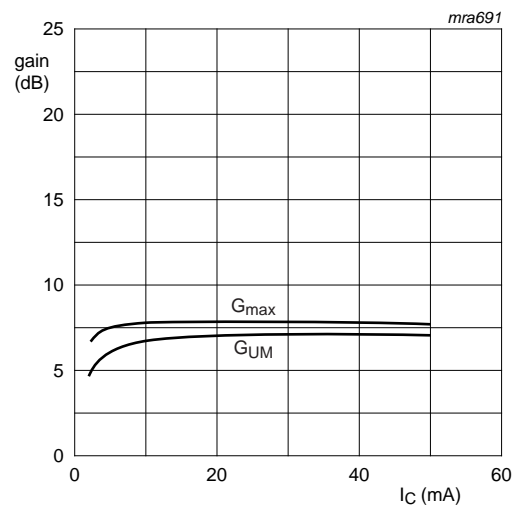
$T_{amb} = 25$  °C;  $f = 1$  GHz.

**Fig. 4. Transition frequency as a function of collector current.**



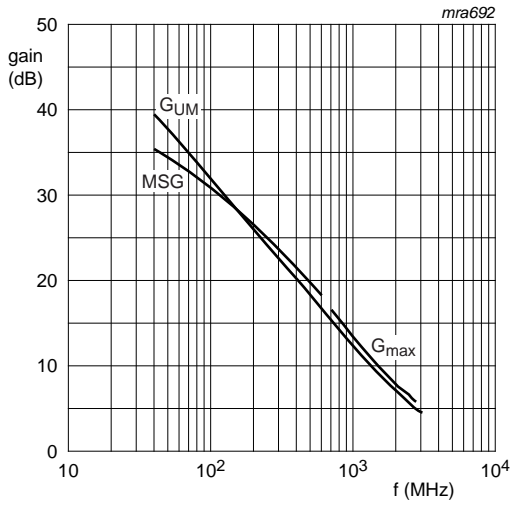
$V_{CE} = 8$  V;  $f = 900$  MHz.

**Fig. 5. Gain as a function of collector current.**



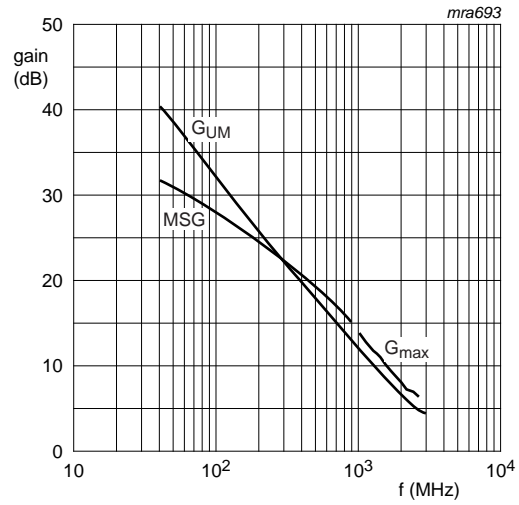
$V_{CE} = 8$  V;  $f = 2$  GHz.

**Fig. 6. Gain as a function of collector current.**



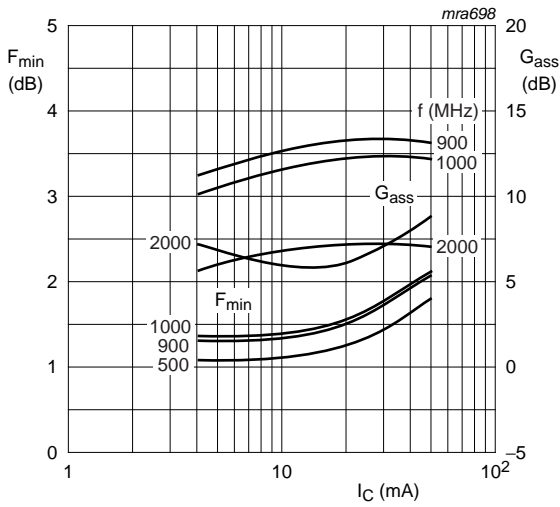
$V_{CE} = 8\text{ V}; I_C = 10\text{ mA}.$

**Fig 7. Gain as a function of frequency;  $I_C = 10\text{ mA}.$**



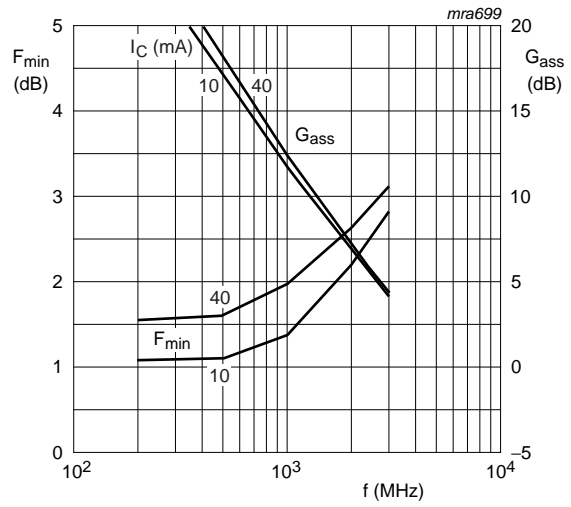
$V_{CE} = 8\text{ V}; I_C = 40\text{ mA}.$

**Fig 8. Gain as a function of frequency;  $I_C = 40\text{ mA}.$**



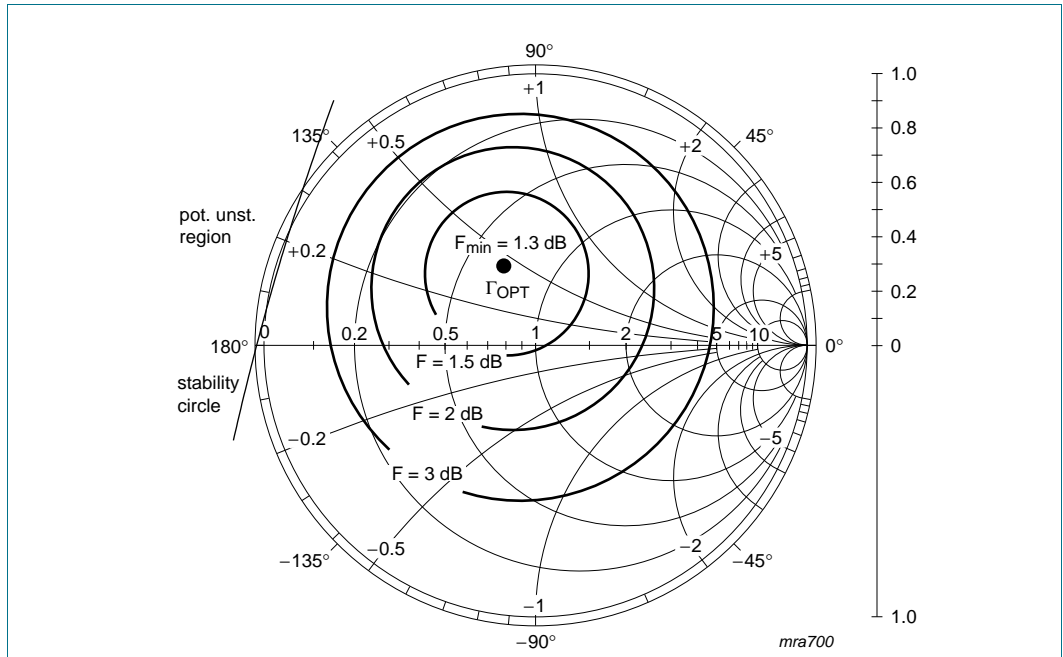
$V_{CE} = 8\text{ V}.$

**Fig 9. Minimum noise figure and associated available gain as a function of collector current.**



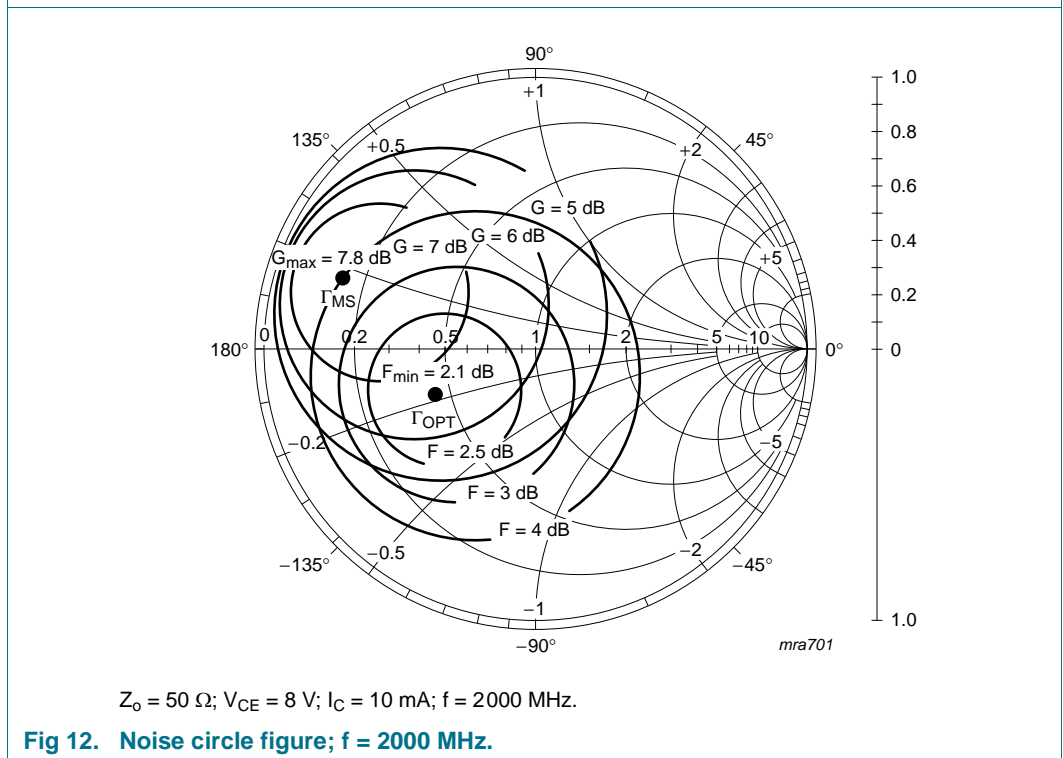
$V_{CE} = 8\text{ V}.$

**Fig 10. Minimum noise figure and associated available gain as a function of frequency.**



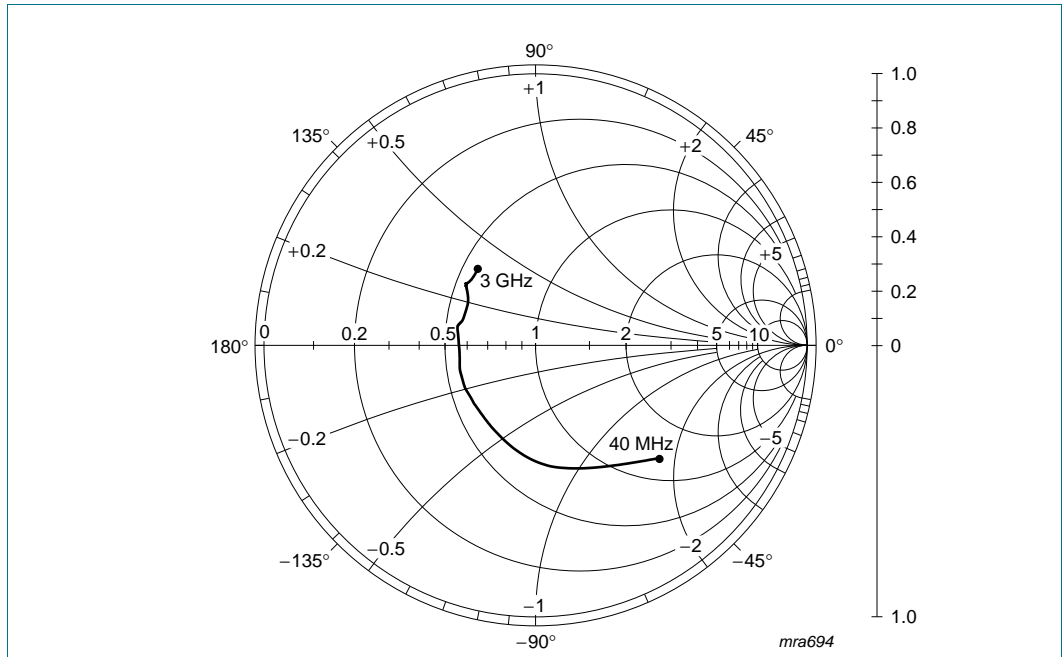
$Z_o = 50 \Omega$ ;  $V_{CE} = 8 V$ ;  $I_C = 10 mA$ ;  $f = 900 MHz$ .

**Fig 11. Noise circle figure;  $f = 900 MHz$ .**



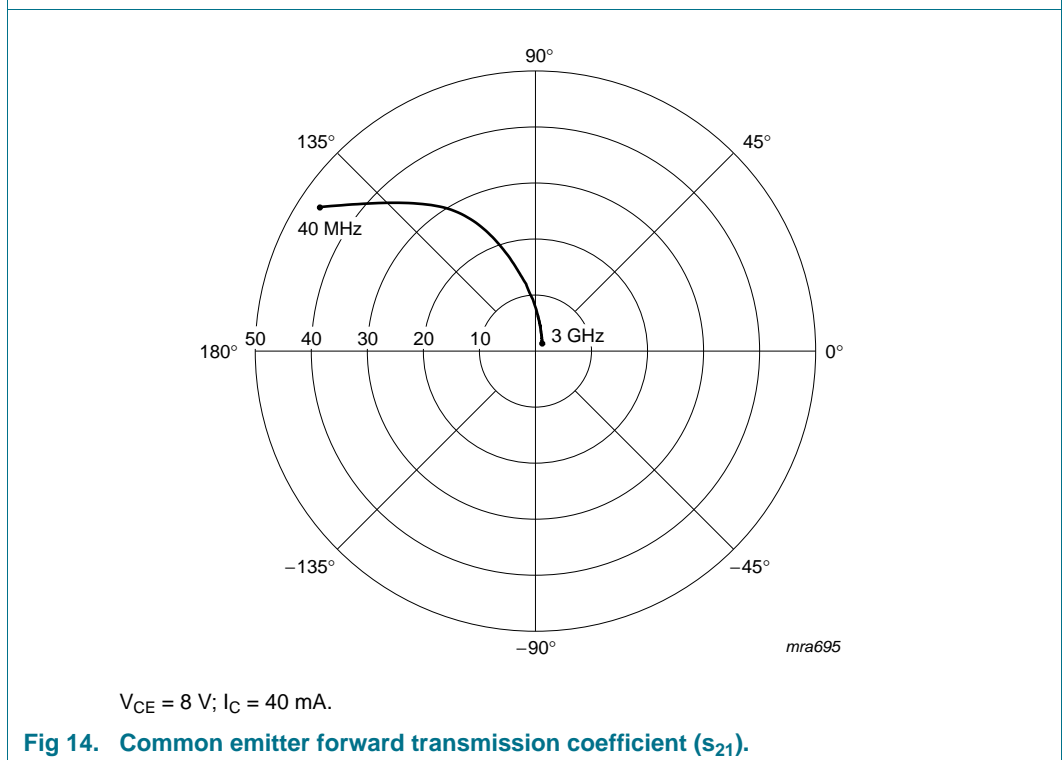
$Z_o = 50 \Omega$ ;  $V_{CE} = 8 V$ ;  $I_C = 10 mA$ ;  $f = 2000 MHz$ .

**Fig 12. Noise circle figure;  $f = 2000 MHz$ .**



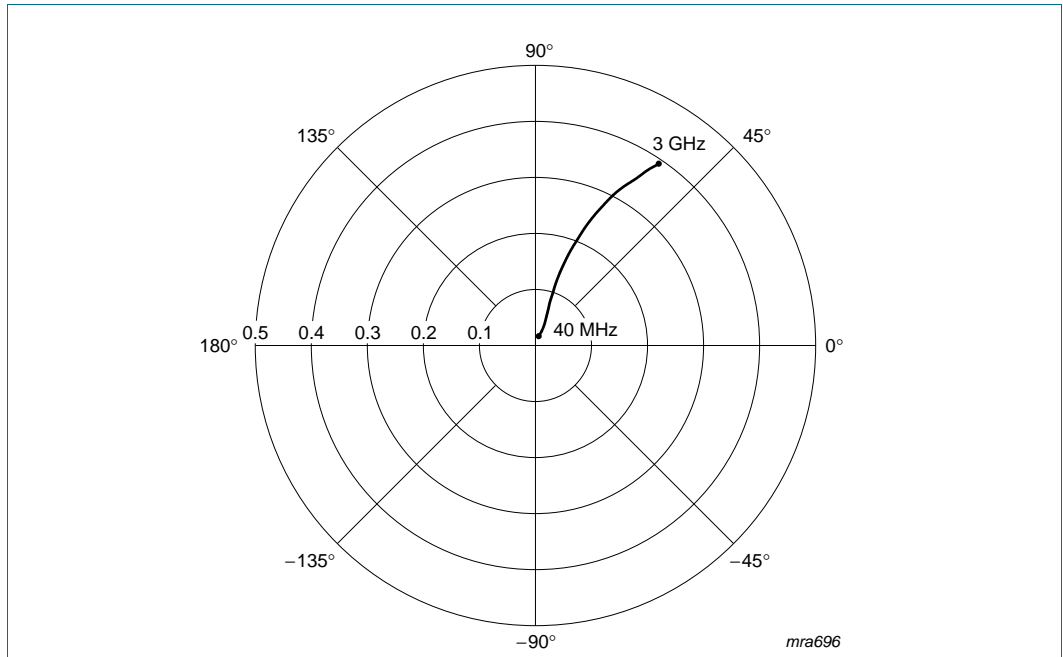
$V_{CE} = 8\text{ V}; I_C = 40\text{ mA}; Z_o = 50\ \Omega.$

**Fig 13. Common emitter input reflection coefficient ( $s_{11}$ ).**



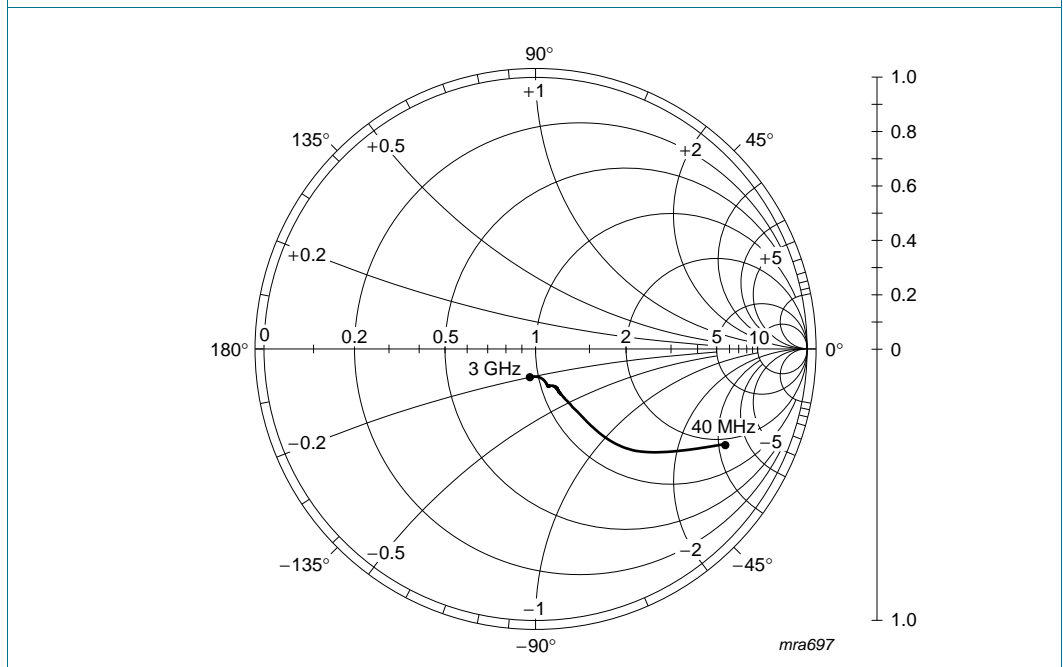
$V_{CE} = 8\text{ V}; I_C = 40\text{ mA}.$

**Fig 14. Common emitter forward transmission coefficient ( $s_{21}$ ).**



$V_{CE} = 8\text{ V}; I_C = 40\text{ mA}$ .

**Fig 15. Common emitter reverse transmission coefficient ( $s_{12}$ ).**



$V_{CE} = 8\text{ V}; I_C = 40\text{ mA}; Z_o = 50\ \Omega$ .

**Fig 16. Common emitter output reflection coefficient ( $s_{22}$ ).**

**8. Package outline**

Plastic surface-mounted package; 3 leads

SOT23

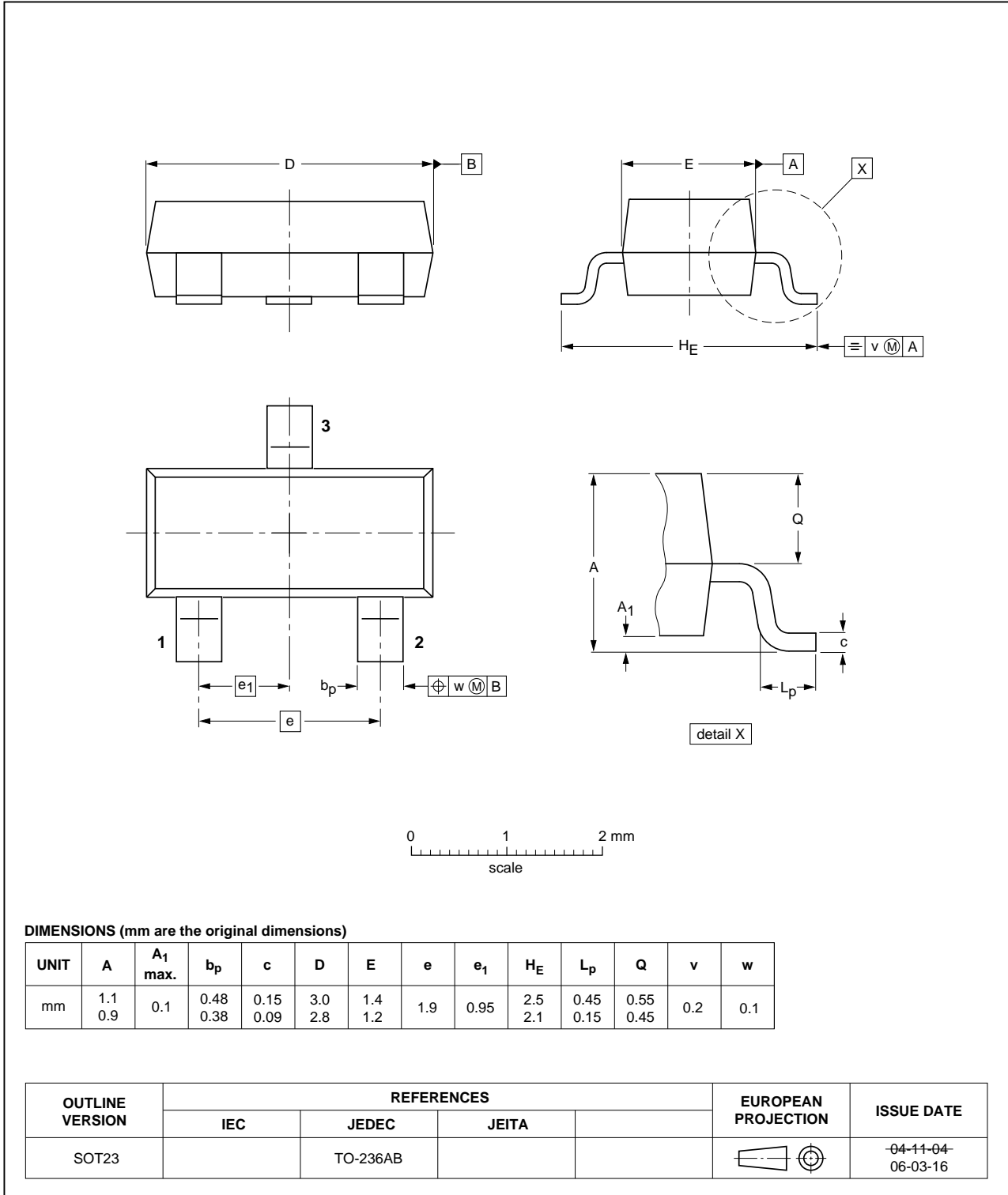


Fig 17. Package outline SOT23 (TO-236AB).

## 9. Revision history

**Table 8. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
BFR540 v.6	20110913	Product data sheet	-	BFR540 v.5
Modifications:		<ul style="list-style-type: none"><li>• The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li><li>• Legal texts have been adapted to the new company name where appropriate.</li><li>• Package outline drawings have been updated to the latest version.</li></ul>		
BFR540 v.5 (9397 750 13398)	20040901	Product data sheet	-	BFR540 v.4
BFR540 v.4 (9397 750 07062)	20000530	Product specification	-	BFR540 v.3
BFR540 v.3 (9397 750 06338)	19990823	Product specification	-	BFR540_CNV v.2
BFR540_CNV v.2	19971204	Product specification	-	-

## 10. Legal information

### 10.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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Date of release: 13 September 2011

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